

claims) are authorized to be charged in two originally-executed copies of an Amendment Transmittal Letter filed herewith. A clean copy of amendments per 37 C.F.R. §1.121 is attached hereto.

Kindly enter the following amendments:

IN THE CLAIMS:

Please amend claims 1, 2, 5, 8, 12, 25 and 26 as follows:

1. (Twice Amended) A reflection type liquid crystal display, comprising:

a pair of substrates disposed opposite to each other with a liquid crystal layer

disposed therebetween;

a plurality of switching elements formed on one surface of at least one of said pair of substrates;

a reflective layer constituted of a same material as ²⁷ *the material of* ²⁸ *an* electrode of said plurality of switching elements and simultaneously formed during formation of said electrode of said plurality of switching elements on a same plane as a plane of said electrode; and

³¹ a transparent pixel electrode formed on said reflective layer via an insulation layer and connected to at least one ²⁶ electrode included in at least one of said plurality of switching elements.

2. (Twice Amended) The reflection type liquid crystal display according to claim 1, wherein said plurality of switching elements includes at least a thin film transistor, and said reflective layer is formed of the same material as a material of [a] ¹¹²⁴ said gate electrode of said thin film transistor and [constituted] formed on the same plane as a plane of ¹¹²⁴ said gate electrode.

5. (Twice Amended) The reflection type liquid crystal display according to claim 1, wherein a shielding layer is disposed on an area of at least one of said plurality of switching elements.

8. (Twice Amended) The reflection type liquid crystal display according to claim 1, wherein said reflective layer is formed of at least one of aluminum and an aluminum alloy.

12. (Once Amended) The reflection type liquid crystal display according to claim 1, wherein [a] at least one rough portion is formed [in the lower layer of] below said reflective layer, and said reflective layer is formed to cover said at least one rough portion.

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Fig 2

25. (Once Amended) A reflection type liquid crystal display, comprising:
a pair of substrates disposed opposite to each other via a liquid crystal layer;
a plurality of switching elements formed on one surface of said pair of substrates;
a reflective layer constituted of a same material as a material constituting ^{112G} said
switching element and simultaneously formed during formation of said switching
elements;

a transparent pixel electrode formed on said reflective layer via an insulation layer
and connected to one electrode constituting ^{112G} said switching element;

wherein ^{112G} said switching element is a thin film transistor, and said reflective layer is
formed of the same material as a material of a gate electrode of said thin film transistor
and constituted on the same plane as a plane of said gate electrode; and

wherein ^{DWG-2} a rough portion is formed [in the lower layer of] below said reflective
layer, and said reflective layer is formed to cover said rough portion.

26. (Once Amended) A reflection type liquid crystal display, comprising:
a pair of substrates disposed opposite to each other via a liquid crystal layer;
a plurality of switching elements formed on one surface of said pair of substrates;
a reflective layer constituted of a same material as a material constituting said ^{112G}
switching element ² and simultaneously formed during formation of said switching
elements;
a transparent pixel electrode formed on said reflective layer via an insulation layer
and connected to one electrode constituting said switching element, ^{112G}
wherein said thin film transistor ^{112G} comprises a gate electrode electrically connected
to a scanning line, a gate insulation film formed to cover said gate electrode, a
semiconductor layer formed on said gate insulation film, a drain electrode electrically
connected to a signal line, and a source electrode electrically connected to said
transparent pixel electrode, and said reflective layer is electrically separated from said
gate electrode; and
wherein a rough portion ^{DWG 2} is formed [in the lower layer of] below said reflective
layer, and said reflective layer is formed to cover said rough portion.

REMARKS

This paper is being provided in response to the January 29, 2002 Final Office Action for the above-referenced application. In this response, applicants have amended claims 1, 2, 5, 8, 12, 25 and 26, in order to more particularly point out and distinctly claim that which applicants deem to be the invention. Applicants respectfully submit that the modifications to the claims are all supported by the originally filed application.